



T1250 Series TCXO

10 MHz to 50 MHz

(Rev A)

GREENRAY INDUSTRIES, INC.

PRECISION QUARTZ TECHNOLOGY

Dual Compensated

SPECIFICATIONS

| | | | |
|--------------------------|--|---------------------|---------------|
| Frequency | 10.0 MHz to 50.0 MHz | | |
| Output | "C" option - CMOS Squarewave; "S" option - Clipped Sinewave | | |
| Load | CMOS - 15pF; Clipped Sinewave – 10pf / 10kohms | | |
| Symmetry | 50% ± 10% (CMOS version) | | |
| Temp Stability | Temp Range | Tolerance | Option |
| | -40 to +85°C | ±3x10 ⁻⁸ | T38 |
| | -40 to +85°C | ±5x10 ⁻⁸ | T58 |
| | -40 to +85°C | ±1x10 ⁻⁷ | T17 |
| | (fmax-fmin)/2xfmin; EFC at center of range. Trim effect ≤ ±0.1ppM over 0 to Vs | | |
| | EFC and temp. Hysteresis not included in stability spec. | | |
| Freq vs. Supply | ±1x10 ⁻⁷ for a 5% change | | |
| Aging | ±5x10 ⁻⁷ per year; <3ppM for 15 years | | |
| Supply V | +5.0 or +3.3 VDC ± 5% | | |
| Input Current | 25mA max | | |
| Phase Noise | Offset | dBc/Hz | |
| (10MHz typ) | 10 Hz | -90 | |
| | 100 Hz | -120 | |
| | 1 kHz | -140 | |
| | 10 kHz | -150 | |
| | 100 kHz | -155 | |
| Accel Sensitivity | ≤2.5x10 ⁻⁹ /g (SD option); or ≤7x10 ⁻¹⁰ /g (LG option) | | |
| Frequency Adjust | ±7ppm typ; via 0 to Vsupply EFC; positive slope | | |
| Environmental | | | |
| | Storage Temp: -55 to +95°C | | |
| | Random Vibration: MIL-STD-202, Meth 214, Cond I-J | | |
| | Sine Vibration: MIL-STD-202, Meth 204, Cond D | | |
| | Shock: MIL-STD-202, Meth 213, Cond F | | |

Ordering Example:

T1250-T58-C-3.3-LG-10MHz
(Model-Stability-Output-InpV-GSense-Freq)

Pad Connections

- 1 - EFC
- 2 - N/C
- 3 - 0 V & Case Gnd
- 4 - Output
- 5 - N/C
- 6 - VSupply

